

CD54HC257, CD74HC257, CD54HCT257

Data sheet acquired from Harris Semiconductor SCHS171D

November 1997 - Revised October 2003

High-Speed CMOS Logic Quad 2-Input Multiplexer with Three-State Non-Inverting Outputs

Features

- · Buffered Inputs
- Typical Propagation Delay (In to Output) = 12ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs............ 10 LSTTL Loads
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC257 and 'HCT257 are quad 2-input multiplexers which select four bits of data from two sources under the control of a common Select Input (S). The Output Enable input (\overline{OE}) is active LOW. When \overline{OE} is HIGH, all of the outputs (1Y-4Y) are in the high impedance state regardless of

all other input conditions.

Moving data from two groups of registers to four common output buses is a common use of the 257. The state of the Select input determines the particular register from which the data comes. It can also be used as a function generator.

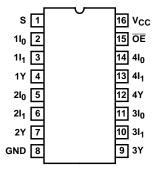
Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE |
|---------------|---------------------|--------------|
| CD54HC257F3A | -55 to 125 | 16 Ld CERDIP |
| CD54HCT257F3A | -55 to 125 | 16 Ld CERDIP |
| CD74HC257E | -55 to 125 | 16 Ld PDIP |
| CD74HC257M | -55 to 125 | 16 Ld SOIC |
| CD74HC257MT | -55 to 125 | 16 Ld SOIC |
| CD74HC257M96 | -55 to 125 | 16 Ld SOIC |
| CD74HCT257E | -55 to 125 | 16 Ld PDIP |
| CD74HCT257M | -55 to 125 | 16 Ld SOIC |
| CD74HCT257MT | -55 to 125 | 16 Ld SOIC |
| CD74HCT257M96 | -55 to 125 | 16 Ld SOIC |

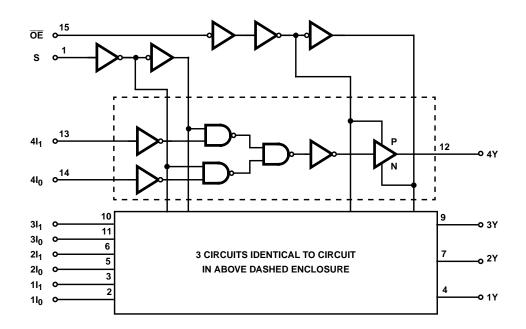
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC257, CD54HCT257 (CERDIP) CD74HC257, CD74HCT257 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

| OUTPUT ENABLE | SELECT INPUT | DATA I | ОИТРИТ | | | |
|------------------|-----------------|----------------|----------------|---|--|--|
| ŌĒ | S | l ₀ | I ₁ | Y | | |
| Н | Х | Х | Х | Z | | |
| L | L | L | Х | L | | |
| L | L | Н | Х | Н | | |
| L | Н | Х | L | L | | |
| L | Н | X | Н | Н | | |

H= High Voltage Level L= Low Voltage Level

X= Don't Care

Z= High Impedance, OFF State

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} -0.5V to 7V DC Input Diode Current, I_{IK} For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ± 20 mA DC Output Diode Current, I_{OK} For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$±20mA DC Drain Current, per Output, IO For $-0.5V < V_O < V_{CC} + 0.5V$±35mA DC Output Source or Sink Current per Output Pin, IO

Thermal Information

| Thermal Resistance (Typical, Note 1) | θ_{JA} (°C/W) |
|--|----------------------|
| E (PDIP) Package | . 67 |
| M (SOIC) Package | |
| Maximum Junction Temperature | 150 ^o C |
| Maximum Storage Temperature Range | -65°C to 150°C |
| Maximum Lead Temperature (Soldering 10s) | 300°C |
| (SOIC - Lead Tips Only) | |

Operating Conditions

| Temperature Range, T _A 55°C to 125°C |
|---|
| Supply Voltage Range, V _{CC} |
| HC Types2V to 6V |
| HCT Types |
| DC Input or Output Voltage, V _I , V _O 0V to V _{CC} |
| Input Rise and Fall Time |
| 2V |
| 4.5V 500ns (Max) |
| 6V |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

| | | TEST CONDITIONS | | | | 25°C | | -40°C T | O 85°C | -55°C TO 125°C | | |
|--------------------------|-----------------|---------------------------|---------------------|---------------------|------|------|------|---------|--------|----------------|-----|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| HC TYPES | | | | | | | - | | | | | |
| High Level Input | V _{IH} | - | - | 2 | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| Voltage | | | | 4.5 | 3.15 | - | - | 3.15 | - | 3.15 | - | V |
| | | | | 6 | 4.2 | - | - | 4.2 | - | 4.2 | - | V |
| Low Level Input | V _{IL} | - | - | 2 | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| Voltage | | | 4.5 | - | - | 1.35 | - | 1.35 | - | 1.35 | V | |
| | | | | 6 | - | - | 1.8 | - | 1.8 | - | 1.8 | V |
| High Level Output | V _{OH} | V _{IH} or | -0.02 | 2 | 1.9 | - | - | 1.9 | - | 1.9 | - | V |
| Voltage CMOS Loads | | V _{IL} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| | | | -0.02 | 6 | 5.9 | - | - | 5.9 | - | 5.9 | - | V |
| High Level Output | 1 | | -6 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Voltage TTL Loads | | | -7.8 | 6 | 5.48 | - | - | 5.34 | - | 5.2 | - | V |
| Low Level Output | V _{OL} | V _{IH} or | 0.02 | 2 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Voltage CMOS Loads | | V_{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| | | | 0.02 | 6 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output | 7 | | 6 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Voltage TTL Loads | | | 7.8 | 6 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | II | V _{CC} or GND | - | 6 | - | - | ±0.1 | - | ±1 | - | ±1 | μА |

DC Electrical Specifications (Continued)

| | | | ST ITIONS | | | 25°C | | -40°C T | O 85°C | -55°C T | O 125°C | |
|--|------------------------------|---------------------------------------|---------------------|---------------------|------|------|------|---------|--------|---------|---------|-------|
| PARAMETER | SYMBOL | V _I (V) | I _O (mA) | V _{CC} (V) | MIN | TYP | MAX | MIN | MAX | MIN | MAX | UNITS |
| Quiescent Device Current | Icc | V _{CC} or GND | 0 | 6 | - | - | 8 | - | 80 | - | 160 | μА |
| Three-State Leakage Current | l _{OZ} | V _{IL} or V _{IH} | - | 6 | - | - | ±0.5 | - | ±5 | - | ±10 | μΑ |
| HCT TYPES | • | | | | | | | | | | | • |
| High Level Input Voltage | V _{IH} | - | - | 4.5 to 5.5 | 2 | - | - | 2 | - | 2 | - | V |
| Low Level Input Voltage | V _{IL} | - | - | 4.5 to 5.5 | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| High Level Output Voltage CMOS Loads | V _{OH} | V _{IH} or V _{IL} | -0.02 | 4.5 | 4.4 | - | - | 4.4 | - | 4.4 | - | V |
| High Level Output Voltage TTL Loads | | | -6 | 4.5 | 3.98 | - | - | 3.84 | - | 3.7 | - | V |
| Low Level Output Voltage CMOS Loads | V _{OL} | V _{IH} or V _{IL} | 0.02 | 4.5 | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| Low Level Output Voltage TTL Loads | | | 6 | 4.5 | - | - | 0.26 | - | 0.33 | - | 0.4 | V |
| Input Leakage Current | II | V _{CC} to GND | 0 | 5.5 | - | - | ±0.1 | - | ±1 | - | ±1 | μΑ |
| Quiescent Device Current | I _{CC} | V _{CC} or GND | 0 | 5.5 | - | - | 8 | - | 80 | - | 160 | μΑ |
| Additional Quiescent Device Current Per Input Pin: 1 Unit Load | ΔI _{CC} (Note 2) | V _{CC} -2.1 | - | 4.5 to 5.5 | - | 100 | 360 | - | 450 | - | 490 | μΑ |
| Three-State Leakage Current | loz | V _{IL} or V _{IH} | - | 5.5 | - | - | ±0.5 | - | ±5 | - | ±10 | μА |

NOTE:

HCT Input Loading Table

| INPUT | UNIT LOADS |
|-------|------------|
| Data | 0.95 |
| S | 3 |
| ŌĒ | 0.6 |

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360 μA max at $25^{o}C.$

^{2.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$

| | | TEST | | 25 | o _C | -40°C TO 85°C | -55°C TO 125°C | |
|--|---------------------------------------|-----------------------|---------------------|-----|----------------|---------------|----------------|----------|
| PARAMETER | SYMBOL | CONDITIONS | V _{CC} (V) | TYP | MAX | MAX | MAX | UNITS |
| HC TYPES | | | | | | | | |
| Propagation Delay In to Y | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | 150 | 190 | 225 | ns |
| III to 1 | | | 4.5 | • | 30 | 38 | 45 | ns |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns |
| | | CL = 50pF | 6 | - | 26 | 33 | 38 | ns |
| Propagation Delay | t _{PLH} , t _{PHL} | C _L = 50pF | 2 | - | 175 | 220 | 265 | ns |
| S to Y | | | 4.5 | - | 35 | 44 | 53 | ns |
| | | C _L = 15pF | 5 | 14 | - | - | - | ns |
| | | CL = 50pF | 6 | - | 30 | 37 | 45 | ns |
| Propagation Delay | t _{PLZ} , t _{PHZ} , | CL = 50pF | 2 | - | 150 | 190 | 225 | ns |
| OE to Y | t _{PZL} , t _{PZH} | C _L = 50pF | 4.5 | - | 30 | 38 | 45 | ns |
| | | C _L = 15pF | 5 | 12 | - | - | - | ns |
| | | CL = 50pF | 6 | - | 26 | 33 | 38 | ns |
| Output Transition Times | t _{TLH} , t _{THL} | C _L = 50pF | 2 | - | 60 | 75 | 90 | ns |
| | | | 4.5 | - | 12 | 15 | 18 | ns |
| | | | 6 | - | 10 | 13 | 15 | ns |
| Input Capacitance | Cl | - | - | - | 10 | 10 | 10 | pF |
| Three-State Output Capacitance | CO | - | - | - | 20 | 20 | 20 | pF |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | - | 5 | 45 | - | - | - | pF |
| HCT TYPES | | | | | ! | | | <u> </u> |
| Propagation Delay | t _{PLH} , t _{PHL} | C _L = 50pF | 4.5 | - | 33 | 41 | 50 | ns |
| In to Y | | C _L = 15pF | 5 | 13 | - | - | - | ns |
| Propagation Delay | t _{PZL} , t _{PZH} | C _L = 50pF | 4.5 | - | 38 | 48 | 57 | ns |
| S to Y | | C _L = 15pF | 5 | 12 | - | - | - | ns |
| Propagation Delay | t _{PLZ} , t _{PHZ} | C _L = 50pF | 4.5 | - | 30 | 38 | 45 | ns |
| OE to Y | | C _L = 15pF | 5 | 16 | - | - | - | ns |
| Output Transition Times | t _{TLH} , t _{THL} | C _L = 50pF | 4.5 | - | 12 | 15 | 18 | ns |
| Input Capacitance | Cl | - | - | - | 10 | 10 | 10 | pF |
| Three-State Output Capacitance | CO | - | - | - | 20 | 20 | 20 | pF |
| Power Dissipation Capacitance (Notes 3, 4) | C _{PD} | - | 5 | 45 | - | - | - | pF |

- 3. C_{PD} is used to determine the dynamic power consumption, per multiplexer. 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

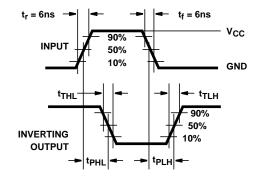


FIGURE 1. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

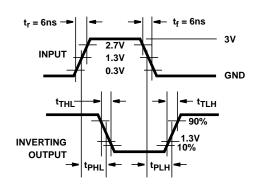


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

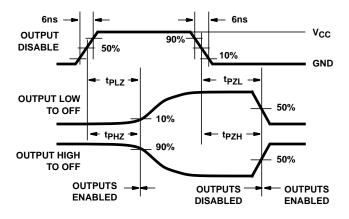


FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM

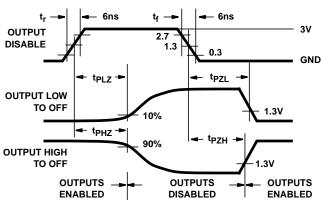
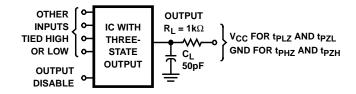


FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

5-Sep-2011

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|------------|--------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| 5962-8970501EA | ACTIVE | CDIP | J | 16 | 1 | TBD | Call TI | Call TI | |
| CD54HC257F3A | ACTIVE | CDIP | J | 16 | 1 | TBD | A42 | N / A for Pkg Type | |
| CD54HCT257F3A | ACTIVE | CDIP | J | 16 | 1 | TBD | A42 | N / A for Pkg Type | |
| CD74HC257E | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| CD74HC257EE4 | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| CD74HC257M | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257M96 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257M96E4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257M96G4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257ME4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257MG4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257MT | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257MTE4 | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HC257MTG4 | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257E | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| CD74HCT257EE4 | ACTIVE | PDIP | N | 16 | 25 | Pb-Free (RoHS) | CU NIPDAU | N / A for Pkg Type | |
| CD74HCT257M | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257M96 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257M96E4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257M96G4 | ACTIVE | SOIC | D | 16 | 2500 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |





5-Sep-2011

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|------------------|-----------------------|--------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| CD74HCT257ME4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257MG4 | ACTIVE | SOIC | D | 16 | 40 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257MT | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257MTE4 | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |
| CD74HCT257MTG4 | ACTIVE | SOIC | D | 16 | 250 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF CD54HC257, CD54HCT257, CD74HC257, CD74HCT257:





www.ti.com 5-Sep-2011

● Catalog: CD74HC257, CD74HCT257

Military: CD54HC257, CD54HCT257

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



TAPE AND REEL INFORMATION





| | Dimension designed to accommodate the component width |
|----|---|
| | Dimension designed to accommodate the component length |
| | Dimension designed to accommodate the component thickness |
| | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|-----------------|--------------------|----|------|--------------------------|--------------------------|---------|---------|---------|------------|-----------|------------------|
| CD74HC257M96 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |
| CD74HCT257M96 | SOIC | D | 16 | 2500 | 330.0 | 16.4 | 6.5 | 10.3 | 2.1 | 8.0 | 16.0 | Q1 |





*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD74HC257M96 | SOIC | D | 16 | 2500 | 333.2 | 345.9 | 28.6 |
| CD74HCT257M96 | SOIC | D | 16 | 2500 | 333.2 | 345.9 | 28.6 |

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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